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Kind regards,

Team Nexperia

PDTA123T series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open

Rev. 02 — 3 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package	Package				
	NXP	JEITA JEDEC				
PDTA123TE	SOT416	SC-75	-	PDTC123TE		
PDTA123TK	SOT346	SC-59A	TO-236	PDTC123TK		
PDTA123TM	SOT883	SC-101	-	PDTC123TM		
PDTA123TS[1]	SOT54	SC-43A	TO-92	PDTC123TS		
PDTA123TT	SOT23	-	TO-236AB	PDTC123TT		
PDTA123TU	SOT323	SC-70	-	PDTC123TU		

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

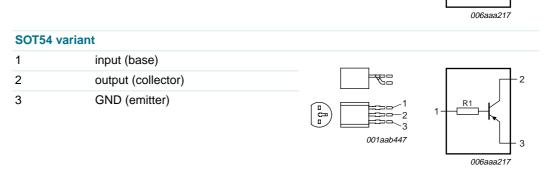
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _O	output current		-	-	-100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	$k\Omega$

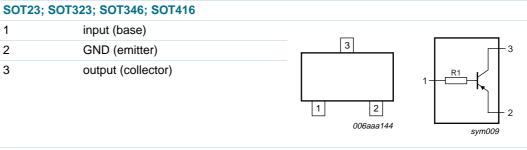


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2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** SOT54 1 input (base) output (collector) 3 GND (emitter) 006aaa217 SOT54A input (base) 2 output (collector) 3 GND (emitter)





		006aaa144	sym009
SOT883			
1	input (base)		
2	GND (emitter)	1 3	3
3	output (collector)	2 Transparent top view	1 R1 2 sym009

3. Ordering information

Table 4. Ordering information

Package					
Name	Description	Version			
SC-75	plastic surface mounted package; 3 leads	SOT416			
SC-59A	plastic surface mounted package; 3 leads	SOT346			
SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883			
SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
-	plastic surface mounted package; 3 leads	SOT23			
SC-70	plastic surface mounted package; 3 leads	SOT323			
	Name SC-75 SC-59A SC-101 SC-43A	Name Description SC-75 plastic surface mounted package; 3 leads SC-59A plastic surface mounted package; 3 leads SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm SC-43A plastic single-ended leaded (through hole) package; 3 leads - plastic surface mounted package; 3 leads			

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

4. Marking

Table 5. Marking codes

indicate in the second	
Type number	Marking code ^[1]
PDTA123TE	2A
PDTA123TK	GA
PDTA123TM	FA
PDTA123TS	TA123T
PDTA123TT	ZL*
PDTA123TU	*1S

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Mir	n Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
lo	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		<u>[1]</u> _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> _	500	mW
	SOT23		<u>[1]</u> _	250	mW
	SOT323		<u>[1]</u> -	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

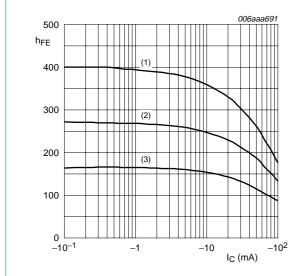
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified

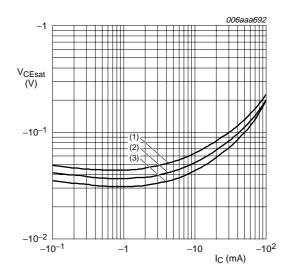
· and						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I_{CEO}	collector-emitter cut-off	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	-1	μΑ
	current	$V_{CE} = -30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -20 \text{ mA}$	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	-	-	-150	mV
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF





- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values

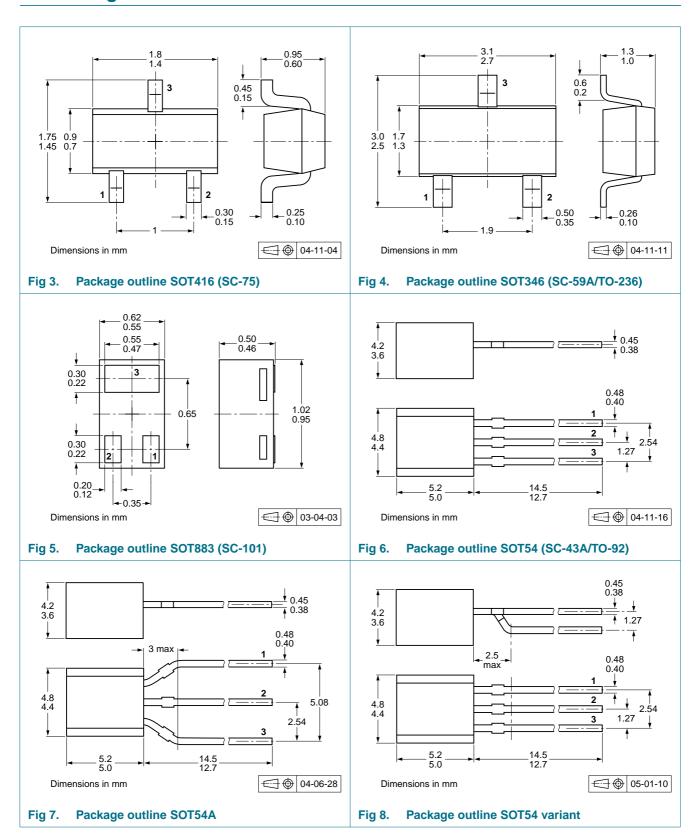


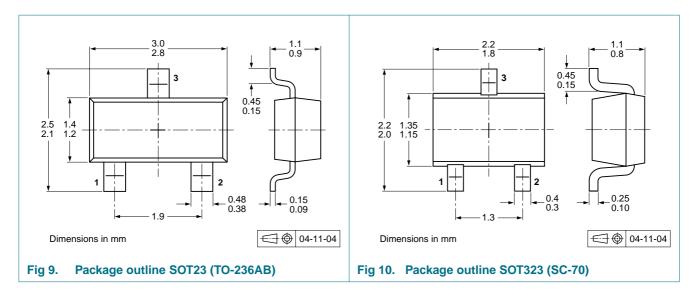
$$I_{\rm C}/I_{\rm B}=20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline





9. Packing information

Table 9. Packing methodsThe indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTA123TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA123TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA123TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA123TS	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide pitch	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-112	-
PDTA123TT	SOT23	4 mm pitch, 8 mm tape and reel	-215		-235
PDTA123TU	SOT323	4 mm pitch, 8 mm tape and reel	-115		-135

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA123T_SER_2	20090903	Product data sheet	-	PDTA123T_SER_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PDTA123T_SER_1	20060307	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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12. Contact information

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PDTA123T series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open

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